

# Low V<sub>CE(sat)</sub> PNP Transistor 60 V, 2 A

# **NSS60200SMT**

**onsemi**'s e<sup>2</sup>PowerEdge family of low  $V_{CE(sat)}$  transistors are miniature surface mount devices featuring ultra low saturation voltage  $(V_{CE(sat)})$  and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and LED lightning, power management...etc. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### **Features**

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- NSV60200SMTWTBG Wettable Flanks Device
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	Vdc
Collector-Base Voltage	$V_{CBO}$	60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6	Vdc
Collector Current - Continuous	Ic	2	Α
Collector Current - Peak	I <sub>CM</sub>	3	Α

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	69	°C/W
Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 1)	$P_{D}$	1.8	W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

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# 60 Volt, 2 Amp PNP Low V<sub>CE(sat)</sub> Transistor

# MARKING DIAGRAM



WDFN6 CASE 506AN

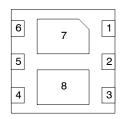


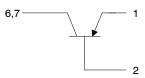
AR = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **PIN CONNECTIONS**





(Pins 3,4,5,8 are not connected)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS60200SMTTBG	WDFN6 (Pb-Free)	3000/Tape & Reel
NSV60200SMTWTBG	WDFN6 (Pb-Free)	3000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>1.</sup> Per JESD51-7 with 100 mm<sup>2</sup> pad area and 2 oz. Cu.

Table 1. ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•	•	•
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	-60			V
Collector-Base Breakdown Voltage (Ic = -0.1 mA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	-80			V
Emitter-Base Breakdown Voltage (I <sub>E</sub> = -0.1 mA, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	-6			V
Collector Cutoff Current (V <sub>CB</sub> = -60 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>			-100	nA
Emitter Cutoff Current (V <sub>BE</sub> = -5.0 V)	I <sub>EBO</sub>			-100	nA
ON CHARACTERISTICS			•	•	•
DC Current Gain (Note 2) $ (I_C = -100 \text{ mA}, V_{CE} = -2.0 \text{ V}) $ $ (I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V}) $ $ (I_C = -1 \text{ A}, V_{CE} = -2.0 \text{ V}) $ $ (I_C = -2 \text{ A}, V_{CE} = -2.0 \text{ V}) $	h <sub>FE</sub>	150 120 90 40	230 180 140 80		
Collector–Emitter Saturation Voltage (Note 2) $ \begin{aligned} &(I_C = -500 \text{ mA}, I_B = -50 \text{ mA}) \\ &(I_C = -700 \text{ mA}, I_B = -7.0 \text{ mA}) \\ &(I_C = -1 \text{ A}, I_B = -50 \text{ mA}) \\ &(I_C = -1 \text{ A}, I_B = -100 \text{ mA}) \\ &(I_C = -2 \text{ A}, I_B = -200 \text{ mA}) \end{aligned} $	V <sub>CE(sat)</sub>		-0.115 -0.295 -0.250 -0.200 -0.365	-0.160 -0.420 -0.350 -0.300 -0.450	V
Base – Emitter Saturation Voltage (Note 2) $ (I_C = -500 \text{ mA}, I_B = -50 \text{ mA}) $ $ (I_C = -1 \text{ A}, I_B = -50 \text{ mA}) $ $ (I_C = -1 \text{ A}, I_B = -100 \text{ mA}) $	V <sub>BE(sat)</sub>			-1.0 -1.0 -1.1	V
Base-Emitter Turn-on Voltage (Note 2) (I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA)	V <sub>BE(on)</sub>			-0.9	V
DYNAMIC CHARACTERISTICS					
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	C <sub>obo</sub>		18		pF
Cutoff Frequency ( $I_C = 50 \text{ mA}$ , $V_{CE} = 2.0 \text{ V}$ , f = 100 MHz)	f <sub>T</sub>		155		MHz
SWITCHING TIMES					
Delay Time ( $V_{CC} = -10 \text{ V}$ , $I_{C} = -0.5 \text{ A}$ , $I_{B1} = -25 \text{ mA}$ , $I_{B2} = 25 \text{ mA}$ )	t <sub>d</sub>		15		ns
Rise Time ( $V_{CC} = -10 \text{ V}$ , $I_{C} = -0.5 \text{ A}$ , $I_{B1} = -25 \text{ mA}$ , $I_{B2} = 25 \text{ mA}$ )	t <sub>r</sub>		13		ns
Storage Time ( $V_{CC} = -10 \text{ V}, I_C = -0.5 \text{ A}, I_{B1} = -25 \text{ mA}, I_{B2} = 25 \text{ mA}$ )	t <sub>s</sub>		360		ns
Fall Time (V <sub>CC</sub> = -10 V, I <sub>C</sub> = -0.5 A, I <sub>B1</sub> = -25 mA, I <sub>B2</sub> = 25 mA)	t <sub>f</sub>		22		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Condition: Pulse Width =  $300 \mu sec$ , Duty Cycle  $\leq 2\%$ 

#### **TYPICAL CHARACTERISTICS**

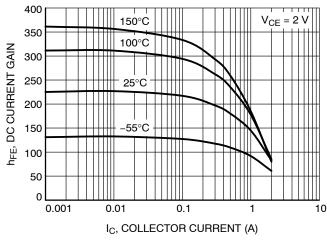


Figure 1. DC Current Gain

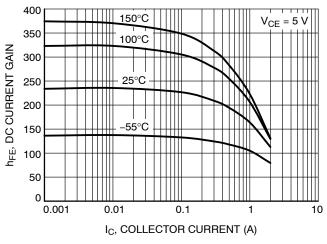


Figure 2. DC Current Gain

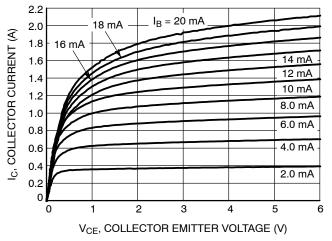


Figure 3. Collector Current as a Function of Collector Emitter Voltage

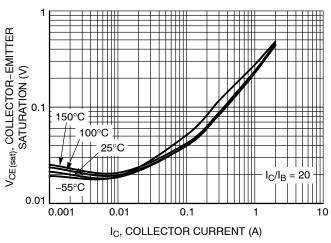


Figure 4. Collector-Emitter Saturation Voltage

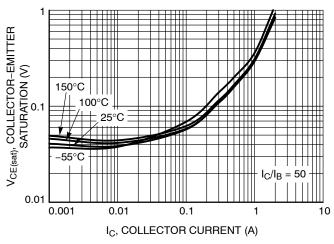


Figure 5. Collector-Emitter Saturation Voltage

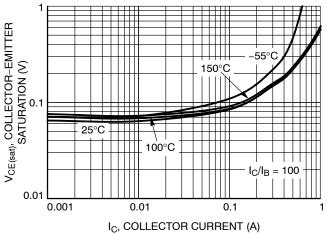


Figure 6. Collector-Emitter Saturation Voltage

#### **TYPICAL CHARACTERISTICS**

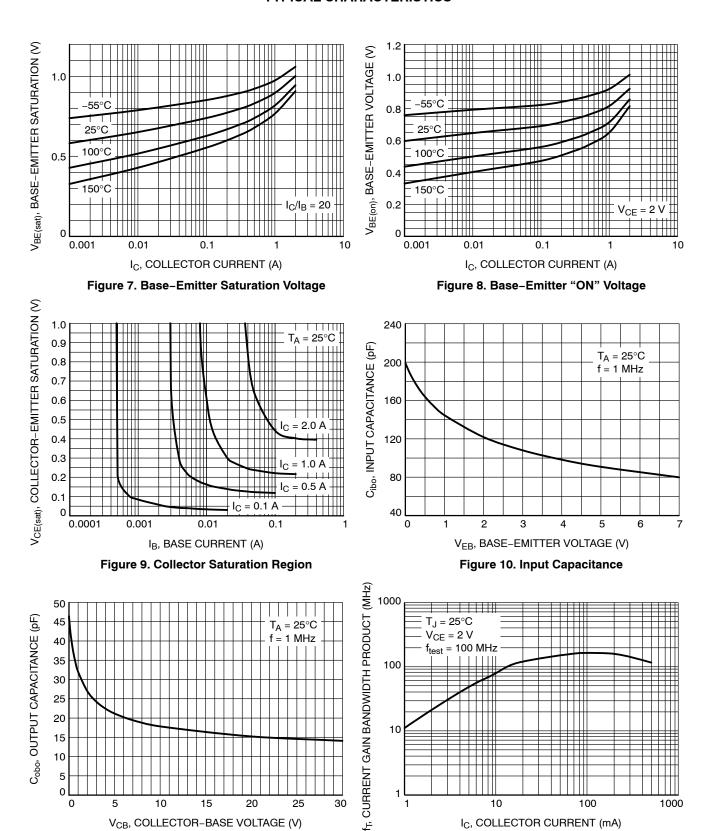


Figure 12. f<sub>T</sub>, Current Gain Bandwidth Product

Figure 11. Output Capacitance

# **TYPICAL CHARACTERISTICS**

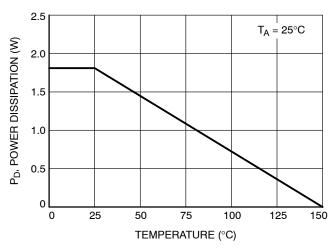


Figure 13. Power Derating

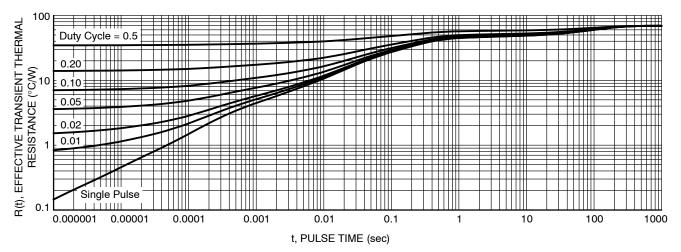


Figure 14. Thermal Resistance by Transistor



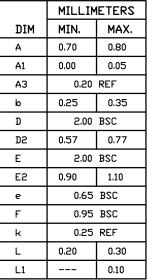


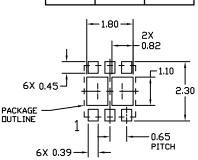
**DATE 25 JAN 2022** 

#### NOTES:

OPTIONAL CONSTRUCTIONS

- 1. DIMENSIONING AND TOLERANCING PER. ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSION 6 APPLIES TO PLATED
  TERMINAL AND IS MEASURED BETWEEN
  0.15 AND 0.30 MM FROM THE TERMINAL TIP.
- 4. COPLANARITY APPLIES TO THE EXPOSED PADS AS WELL AS THE TERMINALS.





RECOMMENDED
MOUNTING FOOTPRINT
SOLDERMASK DEFINED

PIN ONE —	A A	В		
REFERENCE			<u> </u>	
[\(\text{\infty}\) [0.10   C]		<u>t</u>		10
<u>□</u> 0.10 c	TOP VIEW		DETA OPTIONAL CO	AIL A NSTRUCTIONS

DETAIL B    0.10   C	SEATING PLANE EXPUSED CUPPER
SIDE VIEW	PLATING COMPOUND
<u></u> Φ 0.10₩ C A B	DETAIL B

(F) (
TL Harden 2x D2
E2
DETAIL A
k 6 114
_
(e) -   -   0.10   C   B
BOTTOM VIEW

# GENERIC MARKING DIAGRAM\*



XX = Specific Device CodeM = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON20861D	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	WDFN6 2x2, 0.65P		PAGE 1 OF 1

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